NSN 5961-01-110-3767

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-110-3767 **Inclosure Material:** Glass and metal **Overall Length:** 0.265 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.096 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

Fiig: A110a0